

## TOTAL DOSE RADIATION TEST

### I. INTRODUCTION

Total dose radiation tests are designed to characterize changes in device performance due to total dose radiation. These tests are not intended to classify maximum radiation tolerance of any particular device, rather, they simply show trends in the critical parameters as a function of total dose. Whether a device meets tolerance requirements is left up to the designer. In many occasions, designers have the ability to circumvent radiation effects by adding appropriate shielding or compensating for the variations in performance.

MIL-STD-883 method 1019 is used as a guideline for these tests. National's gamma radiation source is kept in compliance with method 1019 and radiation test samples are irradiated under dose rate condition A, which tests for total-dose effects. Samples are kept biased while irradiating. Dose rate is maintained between 50 - 300 Rads(Si)/sec and all samples are exposed to a total dose of 200 kRads(Si).

### II. RADIATION SOURCE

#### A. Type

Atomic Energy of Canada Limited cobalt 60 irradiation unit model Gammacell 220 is used to irradiate the devices under test. The Gammacell 220 produces gamma radiation photons approximately 1.25MeV in energy. Dose rate in the gammacell is maintained between 50 and 300 Rads(Si)/sec with an accuracy of +/- 10%.

#### B. Dosimetry

Thermoluminescence Dosimetry is performed according to MIL-STD-883 method 1019. Actual dose rate for individual test is calculated from the exponential decay approximation of the dosimetry data.

### III. TEST SETUP AND PROCEDURE

#### A. Pre-radiation Electrical Test

All test samples are verified to be functionally and parametrically working prior to irradiation. They are subject to group A qualification test including burn in. Samples are also verified to be within room temperature acceptance limits.

#### B. Test Environment

Samples are enclosed in a lead/aluminum container vertically aligned with the source of radiation while being irradiated. Ambient temperature throughout the test is approximately 25°C.

#### C. Biasing

All devices under test are kept biased during irradiation. Bias circuit used for burn-in is also used for irradiation.

#### C. Electrical Test

Remote electrical tests are performed on the irradiated devices at several total dose levels. All samples are short circuited while transporting to the automatic electrical tester. Electrical tests are completed within two hours of each irradiation step.

### IV. DATA PRESENTATION

A Test Summary sheet provides details on the origins of test samples, dose rate, list of parameters tested and total variation in those parameters. Details of the test consists of select device parameter plotted and tabulated as a function of total dose. Test conditions for each parameter are also specified. Acceptance limits specified in RETS or MDS are also plotted on the graph for reference purpose.

This RHA report is supplied only as a guideline to demonstrate the characteristics of our product in a Total Dose Radiation environment. The results reported are representative only of the lot tested in this specific sample and should not be used as generic RHA qualification data. National Semiconductor uses different process flows for different product qualification levels, and National Semiconductor will not guarantee the RHA performance of any product unless National Semiconductor has tested and certified the specific manufacturing lot. At each radiation exposure level, minimum and maximum shows a plausible variation in the parameter values. It is important to remember that this variation includes variation due to radiation exposure as well as variation between lots and variation between wafers. Measurement variation is assumed insignificant. Whenever possible, radiation test reports will provide an estimate of the percentage of total variation that can be attributed to radiation exposure. This estimate is calculated by analysis of variance (ANOVA) or similar statistical method.

# LM1575J-ADJ

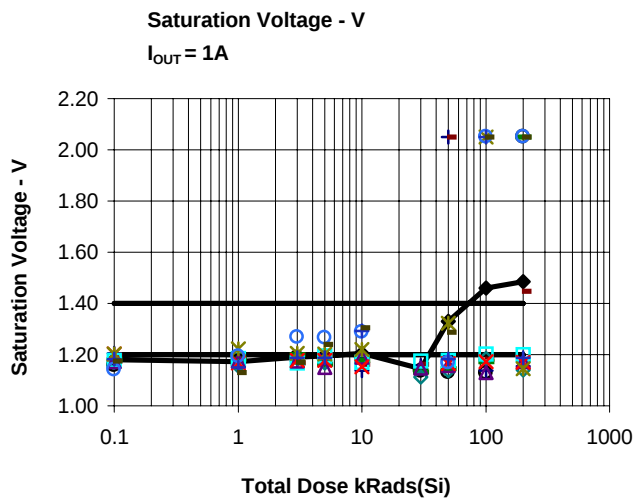
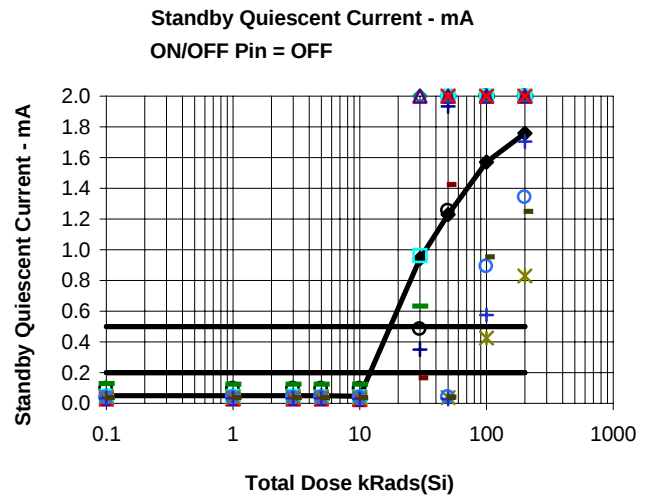
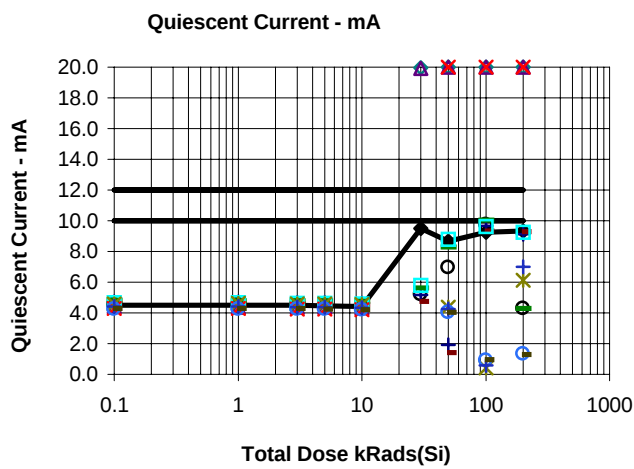
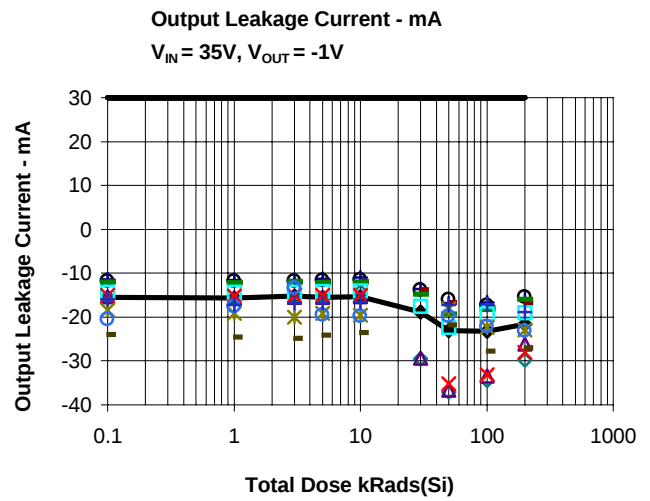
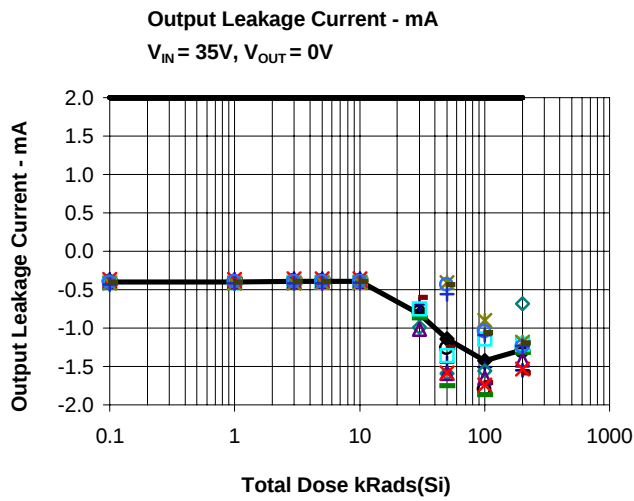
## Total Dose Radiation Test

| Parameter <sup>1</sup>                                                       | Symbol     | Test # | %Δ<br>Post 200k Rad(Si) <sup>2</sup> | Comments                                                     |
|------------------------------------------------------------------------------|------------|--------|--------------------------------------|--------------------------------------------------------------|
| Feedback Voltage                                                             | $V_{OUT}$  | 44     | 24                                   |                                                              |
| Feedback Voltage<br>0.2A $\leq I_{LOAD} \leq 1A$ , 8V $\leq V_{IN} \leq 40V$ | $V_{OUT}$  | 45     | 178                                  |                                                              |
| Feedback Voltage<br>0.2A $\leq I_{LOAD} \leq 1A$ , 8V $\leq V_{IN} \leq 40V$ | $V_{OUT}$  | 46     | 165                                  |                                                              |
| Feedback Voltage<br>0.2A $\leq I_{LOAD} \leq 1A$ , 8V $\leq V_{IN} \leq 40V$ | $V_{OUT}$  | 47     | -20                                  |                                                              |
| Feedback Voltage<br>0.2A $\leq I_{LOAD} \leq 1A$ , 8V $\leq V_{IN} \leq 40V$ | $V_{OUT}$  | 48     | -21                                  |                                                              |
| Saturation Voltage<br>$I_{OUT} = 1A$                                         | $V_{SAT}$  | 43     | 26                                   |                                                              |
| Output leakage Current<br>$V_{IN} = 35V$ , $V_{OUT} = 0V$                    | $I_L$      | 8      | 221                                  |                                                              |
| Output leakage Current<br>$V_{IN} = 35V$ , $V_{OUT} = -1V$                   | $I_L$      | 9      | 39                                   |                                                              |
| Quiescent Current                                                            | $I_Q$      | 10     | 107                                  |                                                              |
| Standby Quiescent Current<br>ON/OFF Pin = OFF                                | $I_{STBY}$ | 11     | 3465                                 |                                                              |
| ON/OFF Pin Threshold Voltage<br>$V_{OUT} = 0V$                               | $V_{IH}$   | 55     | N/A                                  | Indirect test, No failures were seen during the irradiation. |
| ON/OFF Pin Threshold Voltage<br>$V_{OUT} = 5V$                               | $V_{IL}$   | 54     | N/A                                  | Indirect test, No failures were seen during the irradiation. |
| ON/OFF Pin Input Current<br>On/OFF Pin = OFF                                 | $I_{IH}$   | 57     | -77                                  |                                                              |

Note 1:  $V_{IN} = 12V$ ,  $I_{LOAD} = 200mA$  unless otherwise specified

Note 2: Percent change between prerad and post 200 kRad average parameter value.

## LM1575J-ADJ Total Dose Characterization



Note: N = 12,  $V_{IN} = 12V$ ,  $I_{LOAD} = 200mA$  unless otherwise stated. MDS - MNLM1575-X-ADJ limits are shown.

## LM1575J-ADJ

### Total Dose Characterization

Output Leakage Current - mA

$V_{IN} = 35V$ ,  $V_{OUT} = 0V$

Limit: 2mA Max.

| Dose | Avg.  | Min.  | Max.  | S. Dev. | Fail <sup>1</sup> |
|------|-------|-------|-------|---------|-------------------|
| 0.1  | -0.40 | -0.43 | -0.37 | 0.02    | 0                 |
| 1    | -0.40 | -0.42 | -0.37 | 0.02    | 0                 |
| 3    | -0.39 | -0.42 | -0.36 | 0.02    | 0                 |
| 5    | -0.39 | -0.42 | -0.36 | 0.02    | 0                 |
| 10   | -0.39 | -0.41 | -0.36 | 0.02    | 0                 |
| 30   | -0.82 | -1.02 | -0.60 | 0.15    | 0                 |
| 50   | -1.14 | -1.75 | -0.41 | 0.52    | 0                 |
| 100  | -1.42 | -1.87 | -0.90 | 0.35    | 0                 |
| 200  | -1.29 | -1.58 | -0.68 | 0.24    | 0                 |

Output Leakage Current - mA

$V_{IN} = 35V$ ,  $V_{OUT} = -1V$

Limit: 30mA Max.

| Dose | Avg.   | Min.   | Max.   | S. Dev. | Fail <sup>1</sup> |
|------|--------|--------|--------|---------|-------------------|
| 0.1  | -15.52 | -23.90 | -11.40 | 3.83    | 0                 |
| 1    | -15.58 | -24.50 | -11.50 | 3.78    | 0                 |
| 3    | -15.23 | -24.80 | -11.50 | 3.92    | 0                 |
| 5    | -15.54 | -24.10 | -11.30 | 3.85    | 0                 |
| 10   | -15.35 | -23.50 | -11.00 | 3.90    | 0                 |
| 30   | -18.90 | -29.50 | -13.60 | 7.33    | 0                 |
| 50   | -23.06 | -37.10 | -16.00 | 8.23    | 0                 |
| 100  | -23.29 | -34.50 | -16.60 | 7.01    | 0                 |
| 200  | -21.56 | -29.80 | -15.30 | 5.28    | 0                 |

Quiescent Current - mA

Limits: 10mA Max. (SG1), 12mA Max. (SG2/3)

| Dose | Avg. | Min. | Max.  | S. Dev. | Fail <sup>1</sup> |
|------|------|------|-------|---------|-------------------|
| 0.1  | 4.50 | 4.27 | 4.82  | 0.18    | 0                 |
| 1    | 4.50 | 4.27 | 4.81  | 0.18    | 0                 |
| 3    | 4.48 | 4.26 | 4.80  | 0.18    | 0                 |
| 5    | 4.47 | 4.25 | 4.78  | 0.18    | 0                 |
| 10   | 4.43 | 4.21 | 4.74  | 0.18    | 0                 |
| 30   | 9.49 | 4.77 | 19.94 | 7.14    | 1                 |
| 50   | 8.67 | 1.42 | 19.98 | 7.17    | 3                 |
| 100  | 9.27 | 0.43 | 19.98 | 7.62    | 4                 |
| 200  | 9.32 | 1.28 | 19.98 | 6.98    | 3                 |

Standby Quiescent Current - mA

ON/OFF Pin = OFF

Limits: 0.2mA Max. (SG1), 0.5mA Max. (SG2/3)

| Dose | Avg.  | Min.  | Max.  | S. Dev. | Fail <sup>1</sup> |
|------|-------|-------|-------|---------|-------------------|
| 0.1  | 0.049 | 0.029 | 0.128 | 0.031   | 0                 |
| 1    | 0.050 | 0.029 | 0.127 | 0.030   | 0                 |
| 3    | 0.049 | 0.028 | 0.127 | 0.030   | 0                 |
| 5    | 0.048 | 0.028 | 0.127 | 0.031   | 0                 |
| 10   | 0.048 | 0.026 | 0.126 | 0.031   | 0                 |
| 30   | 0.942 | 0.166 | 1.998 | 0.762   | 3                 |
| 50   | 1.229 | 0.028 | 1.998 | 0.913   | 8                 |
| 100  | 1.569 | 0.425 | 1.998 | 0.647   | 12                |
| 200  | 1.759 | 0.830 | 1.998 | 0.400   | 12                |

Saturation Voltage - V

$I_{OUT} = 1A$

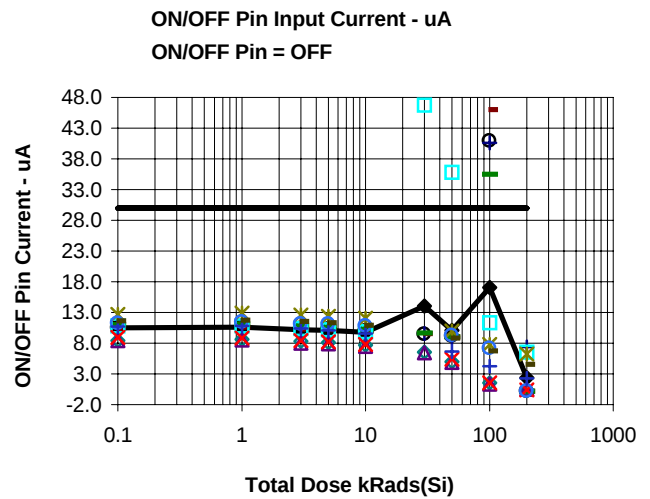
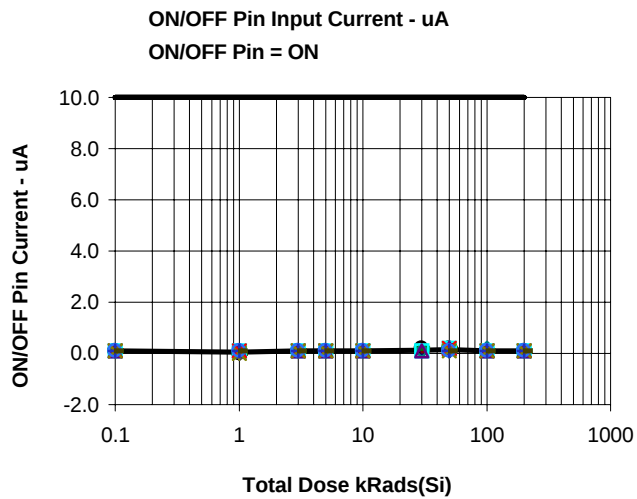
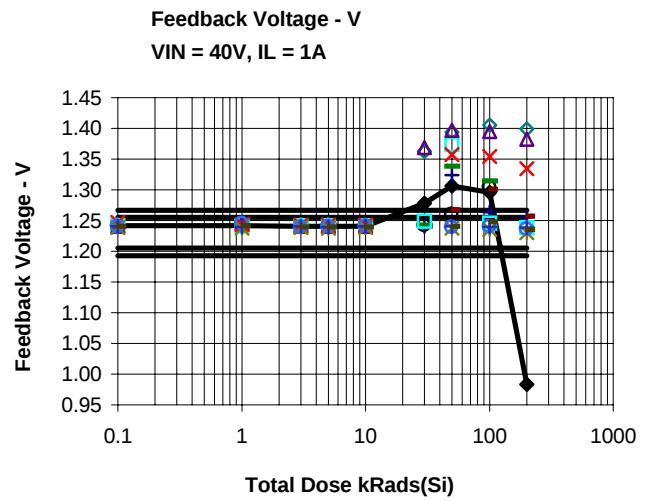
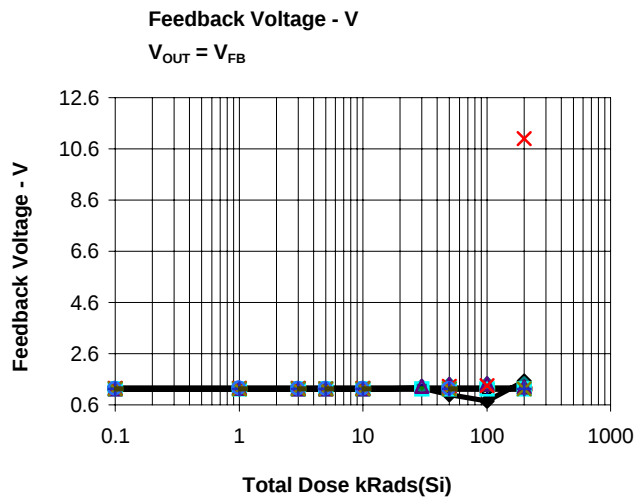
Limits: 1.2V Max. (SG1), 1.4V Max. (SG2/3)

| Dose | Avg.  | Min.  | Max.  | S. Dev. | Fail <sup>1</sup> |
|------|-------|-------|-------|---------|-------------------|
| 0.1  | 1.180 | 1.139 | 1.204 | 0.020   | 0                 |
| 1    | 1.172 | 1.131 | 1.223 | 0.023   | 1                 |
| 3    | 1.189 | 1.169 | 1.267 | 0.027   | 2                 |
| 5    | 1.194 | 1.150 | 1.266 | 0.032   | 2                 |
| 10   | 1.206 | 1.138 | 1.306 | 0.058   | 4                 |
| 30   | 1.146 | 1.112 | 1.175 | 0.021   | 0                 |
| 50   | 1.331 | 1.130 | 2.051 | 0.341   | 4                 |
| 100  | 1.459 | 1.128 | 2.051 | 0.437   | 4                 |
| 200  | 1.485 | 1.140 | 2.051 | 0.426   | 4                 |

Note: N = 12,  $V_{IN} = 12V$ ,  $I_{LOAD} = 200mA$  unless otherwise stated. MDS - MNLM1575-X-ADJ limits are shown.

Note 1: Number of devices that were outside MDS sub group 1 limits.

## LM1575J-ADJ Total Dose Characterization



Note: N = 12,  $V_{IN} = 12V$ ,  $I_{LOAD} = 200mA$  unless otherwise stated. MDS - MNLM1575-X-ADJ limits are shown.

## LM1575J-ADJ

### Total Dose Characterization

Feedback Voltage - V

$$V_{OUT} = V_{FB}$$

Limits: 1.217 - 1.243 V (SG1)

| Dose | Avg.  | Min.   | Max.   | S. Dev. | Fail <sup>1</sup> |
|------|-------|--------|--------|---------|-------------------|
| 0.1  | 1.236 | 1.233  | 1.242  | 0.002   | 0                 |
| 1    | 1.237 | 1.232  | 1.242  | 0.003   | 0                 |
| 3    | 1.236 | 1.233  | 1.238  | 0.001   | 0                 |
| 5    | 1.235 | 1.232  | 1.238  | 0.002   | 0                 |
| 10   | 1.235 | 1.233  | 1.238  | 0.001   | 0                 |
| 30   | 1.260 | 1.234  | 1.324  | 0.043   | 2                 |
| 50   | 1.003 | -0.374 | 1.405  | 0.646   | 5                 |
| 100  | 0.739 | -0.372 | 1.422  | 0.823   | 7                 |
| 200  | 1.528 | -0.374 | 10.994 | 3.083   | 6                 |

Feedback Voltage - V

$$V_{IN} = 40V, I_L = 1A$$

Limits: 1.205 - 1.255 V (SG1), 1.193 - 1.267 V (SG2,3)

| Dose | Avg.  | Min.   | Max.  | S. Dev. | Fail <sup>1</sup> |
|------|-------|--------|-------|---------|-------------------|
| 0.1  | 1.241 | 1.238  | 1.247 | 0.002   | 0                 |
| 1    | 1.242 | 1.237  | 1.245 | 0.002   | 0                 |
| 3    | 1.241 | 1.239  | 1.243 | 0.001   | 0                 |
| 5    | 1.241 | 1.238  | 1.243 | 0.002   | 0                 |
| 10   | 1.241 | 1.238  | 1.243 | 0.001   | 0                 |
| 30   | 1.278 | 1.241  | 1.369 | 0.060   | 2                 |
| 50   | 1.306 | 1.237  | 1.397 | 0.065   | 8                 |
| 100  | 1.296 | 1.235  | 1.405 | 0.061   | 6                 |
| 200  | 0.984 | -0.502 | 1.399 | 0.696   | 6                 |

ON/OFF Pin Input Current - uA

ON/OFF Pin = ON

Limit 10uA Max.

| Dose | Avg. | Min. | Max. | S. Dev. | Fail <sup>1</sup> |
|------|------|------|------|---------|-------------------|
| 0.1  | 0.10 | 0.10 | 0.10 | 0.00    | 0                 |
| 1    | 0.06 | 0.00 | 0.10 | 0.05    | 0                 |
| 3    | 0.10 | 0.10 | 0.10 | 0.00    | 0                 |
| 5    | 0.10 | 0.10 | 0.10 | 0.00    | 0                 |
| 10   | 0.10 | 0.10 | 0.10 | 0.00    | 0                 |
| 30   | 0.13 | 0.10 | 0.20 | 0.05    | 0                 |
| 50   | 0.16 | 0.10 | 0.20 | 0.05    | 0                 |
| 100  | 0.11 | 0.10 | 0.20 | 0.03    | 0                 |
| 200  | 0.10 | 0.10 | 0.10 | 0.00    | 0                 |

ON/OFF Pin Input Current - uA

ON/OFF Pin = OFF

Limit 30uA Max.

| Dose | Avg.  | Min. | Max.  | S. Dev. | Fail <sup>1</sup> |
|------|-------|------|-------|---------|-------------------|
| 0.1  | 10.45 | 8.40 | 12.70 | 1.29    | 0                 |
| 1    | 10.57 | 8.50 | 12.90 | 1.32    | 0                 |
| 3    | 10.23 | 8.00 | 12.60 | 1.37    | 0                 |
| 5    | 10.08 | 7.90 | 12.40 | 1.37    | 0                 |
| 10   | 9.73  | 7.50 | 12.10 | 1.40    | 0                 |
| 30   | 14.01 | 6.40 | 46.80 | 14.53   | 0                 |
| 50   | 10.13 | 4.90 | 35.80 | 8.29    | 0                 |
| 100  | 17.05 | 1.30 | 46.00 | 17.89   | 0                 |
| 200  | 2.43  | 0.20 | 7.40  | 2.89    | 0                 |

Note: N = 12,  $V_{IN}$  = 12V,  $I_{LOAD}$  = 200mA unless otherwise stated. MDS - MNLM1575-X-ADJ limits are shown.

Note 1: Number of devices that were outside MDS sub group 1 limits.